

INTERNATIONAL RECTIFIER

60HFU... SERIES

SUPER FAST RECTIFIER DIODE 60 Amp 60ns

Major ratings and characteristics

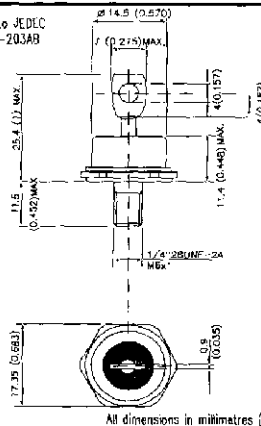
	60HFU	Units
I_F (AVG)	60	A
T_c	82	°C
I_{RMS}	94	A
I_{FSM} @ 10ms	830	A
I_{FSM} @ 8.3ms	870	A
V_{RRM}	100 to 600	V
T_J	-40 to 125	°C

Description and Features

- Very low reverse recovery time
- Reduced switching losses
- Soft recovery characteristics
- High surge current capability
- No voltage derating up to 150°C
- Stud cathode and stud anode versions
- Designed for switching applications:
Free wheeling diode in converters and control circuits
Rectifier in S.M.P.S.



Conforms to JEDEC
Outline DO-203AB
(00-5)



ELECTRICAL SPECIFICATIONS
Forward Conduction

Parameters	Value	Units	Conditions
$I_{(AV)}$ Maximum average forward current	60	A	180° conduction, half sine cond @ Case temperature = 82°C
	67	A	180° conduction, rect cond @ Case temperature = 82°C
$I_{(RMS)}$ Maximum RMS current	94	A	
$I_{(SM)}$ Maximum peak, one-cycle non-repetitive forward current Initial $I_1 = I_{(SM)}$ max.	830	A	$t = 10ms$ No voltage reapplied
	870	A	$t = 8.3ms$
	700	A	$t = 10ms$ 100% $V_{(RM)}$ reapplied
	730	A	$t = 8.3ms$
R Maximum PR for fusing Initial $T_J = T_J$ max.	3460	A ² s	$t = 10ms$ No voltage reapplied
	3190	A ² s	$t = 8.3ms$
	2456	A ² s	$t = 10ms$ 100% $V_{(RM)}$ reapplied
	2240	A ² s	$t = 8.3ms$
PNV Maximum PNV for fusing	34800	JAN ²	$t = 0$ to 10ms, no voltage reapplied
$V_{(T0)}$ Maximum value of the estate voltage	1.08	V	$T = 125°C$
$r_{(T)}$ Maximum value of forward static resistance	3.40	m Ω	$T = 125°C$
$V_{(d)}$ Maximum forward voltage drop	1.50	V	$I_{(M)} = 60 \text{ Apk}$ $T_J = 25°C$
	1.30	V	$I_{(M)} = 60 \text{ Apk}$ $T_J = 125°C$

Thermal and Mechanical Specifications

T_J Junction temperature range	-40 to 125	°C	
$T_{(STG)}$ Storage temperature range	-40 to 150	°C	
$R_{(JC)}$ Maximum thermal resistance junction to case	0.36	K/W	DC operation per junction
$R_{(HS)}$ Maximum thermal resistance, case to heatsink	0.25	K/W	Mounting surface, smooth and greased
T Mounting torque, base to heatsink $\pm 10\%$	2.5	Nm	A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound
w Approximate weight	25	g	

Recovery Characteristics

Parameters	Typ.	Max.	Units	Conditions
t_{rr} Recovery time	60	80	ns	$T_J = 25°C$ IF = 1A, $dI/dt = -100 \text{ A}/\mu\text{s}$, $V_r = -30V$
Q_{rr} Recovered charge	250	300	nC	$T_J = 25°C$ IF = 1A, $dI/dt = -100 \text{ A}/\mu\text{s}$, $V_r = -30V$

Voltage ratings ($T_J = T_J$ max.)

Type number	$V_{(RRM)}$ - maximum repetitive peak reverse voltage	$V_{(NSM)}$ - maximum non-repetitive peak reverse voltage	$I_{(SM)}$ Max @ 100°C	$I_{(SM)}$ Max @ 150°C	$I_{(SM)}$ Typ. @ 25°C
	V	V	mA	mA	μA
60HFU(R)-100	100	110	5	15	50
60HFU(R)-200	200	220	5	15	50
60HFU(R)-300	300	330	5	15	50
60HFU(R)-400	400	440	5	15	50
60HFU(R)-500	500	550	5	25	50
60HFU(R)-600	600	660	5	25	50

ΔR Conduction (per junction)

(The following table shows the increment of thermal resistance $R_{th(j-c)}$ when devices operate at different conduction angles than DC.)

Conduction angle	Sinusoidal Conduction	Rectangular Conduction	Units	Conditions
180°	0.06	0.06	K/W	
120°	0.08	0.09	K/W	
90°	0.10	0.12	K/W	
60°	0.13	0.16	K/W	
30°	0.24	0.24	K/W	

Fig.1 - Maximum Forward Energy Loss Per Pulse Characteristics

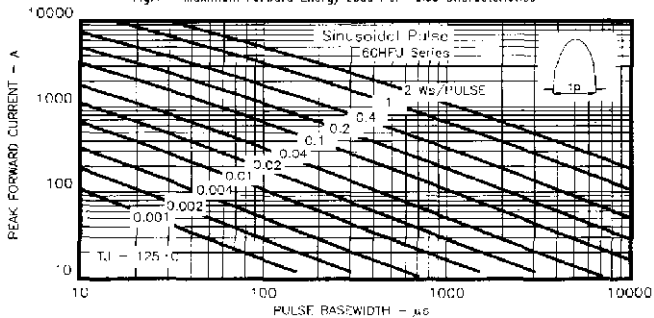
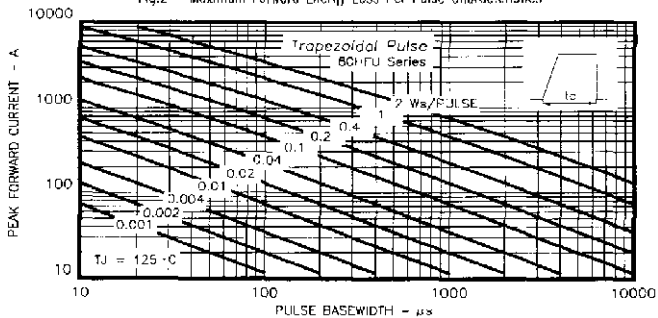
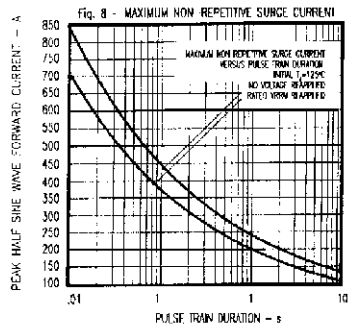
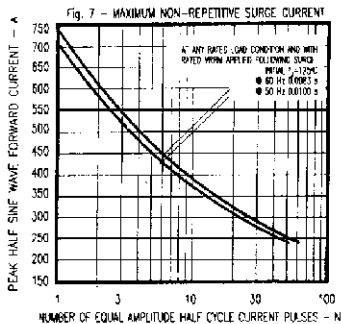
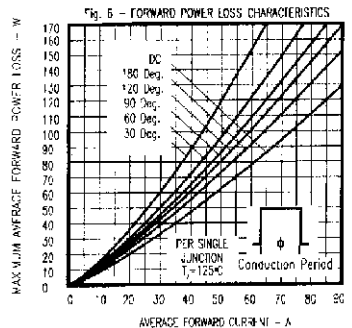
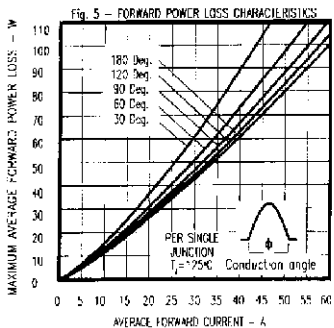
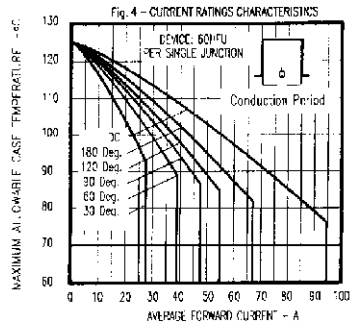
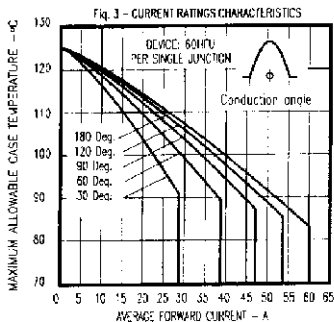
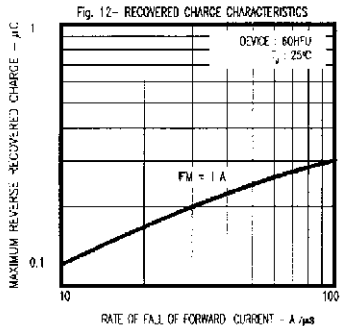
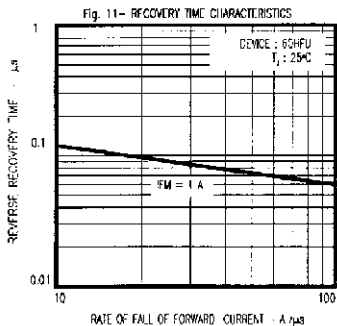
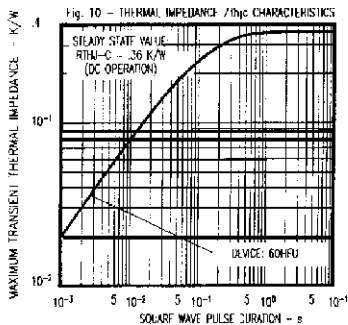
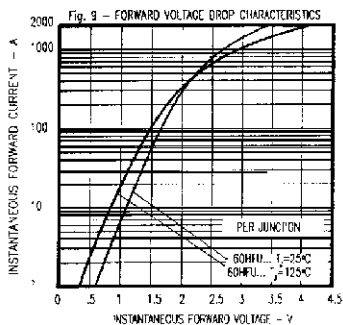


Fig.2 - Maximum Forward Energy Loss Per Pulse Characteristics









Notice

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